

Product data sheet

1. General description

Planar passivated sensitive gate four quadrant triac in a SOT223 surface-mountable plastic package intended for applications requiring enhanced immunity to noise and direct interfacing to logic level ICs and low power gate drivers.

2. Features and benefits

- Direct interfacing to logic level ICs
- · Enhanced current surge capability
- Enhanced noise immunity
- High blocking voltage capability
- Planar passivated for voltage ruggedness and reliability
- Sensitive gate in four quadrants
- Surface-mountable package
- Triggering in all four quadrants

3. Applications

- General purpose low power motor control
- Home appliances
- Industrial process control
- Low power AC Fan controllers

4. Quick reference data

Table 1. Q	uick reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
V_{DRM}	repetitive peak off-state voltage		-	-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	13.8	А
Tj	junction temperature		-	-	125	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 9}$	0.4	-	10	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 9}$	0.4	-	10	mA

Z0109NN0

4Q Triac

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 9}$	0.4	-	10	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 9}$	0.4	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	-	10	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 12</u>	-	1.3	1.6	V
Dynamic	characteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 110 °C; (V_{DM} = 67% of V_{DRM}); exponential waveform; gate open circuit; Fig. 14	120	-	-	V/µs
dV_{com}/dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	2	-	-	V/µs

5. Pinning information

Table 2. Pinning information								
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	T1	main terminal 1		Ν				
2	T2	main terminal 2						
3	G	gate		sym051				
4	T2	main terminal 2						

6. Ordering information

Table 3. Ordering information								
Type number	Package	Orderable part number	Packing	Small packing	Package	Package		
	Name		method	quantity	version	issue date		
Z0109NN0	SOT223	Z0109NN0,135	Reel	4000	SOT223	16-Mar-2006		

7. Marking

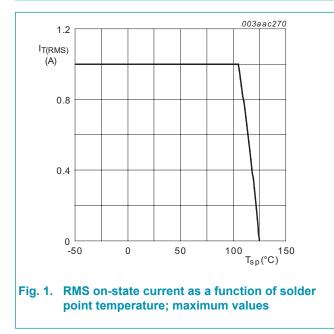
Type number	Marking codes			
	Assembly factory: d	Assembly factory: L		
Z0109NN0	Jdxxx 109NN0	JLxxx 109NN0		

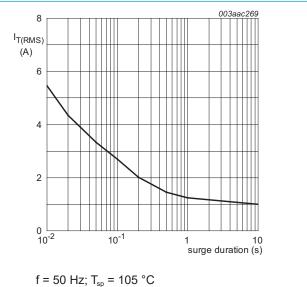
8. Limiting values

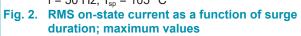
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

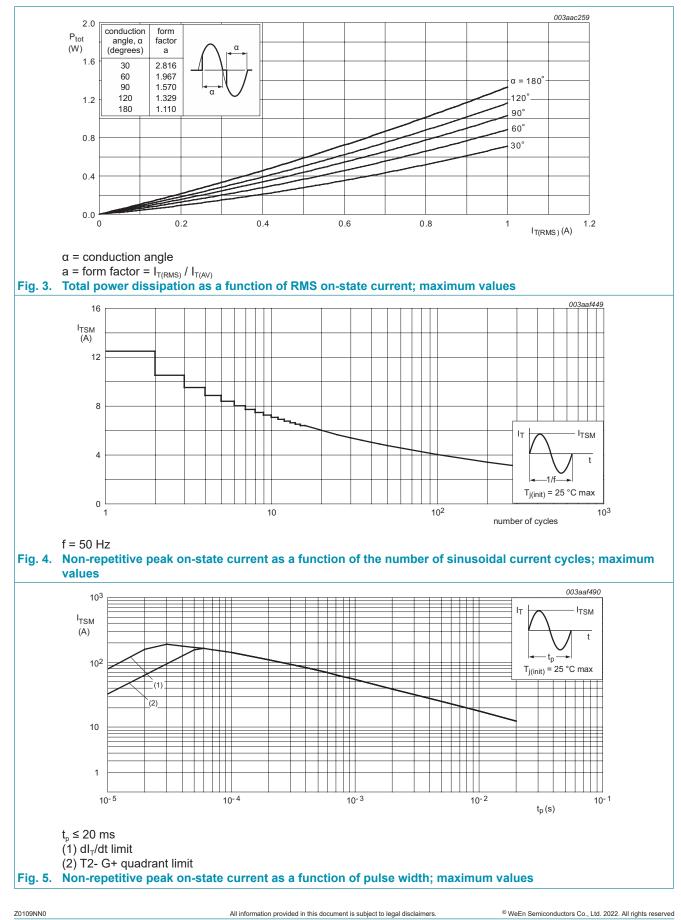
Symbol	Parameter	Conditions	Min	Max	Unit
V _{drm}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{sp} ≤ 105 °C; <u>Fig 1; Fig 2</u> ; <u>Fig 3</u>	-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; Fig 4; Fig 5	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	13.8	А
l ² t	l ² t for fusing	t _p = 10 ms; SIN	-	0.78	A ² s
dl _⊤ /dt	rate of rise of on-state current	I _G = 20 mA; T2+ G+	-	50	A/µs
		I _G = 20 mA; T2- G+	-	50	A/µs
		I _G = 20 mA; T2- G-	-	50	A/µs
		I _G = 20 mA; T2- G+	-	20	A/µs
I _{GM}	peak gate current		-	1	А
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C





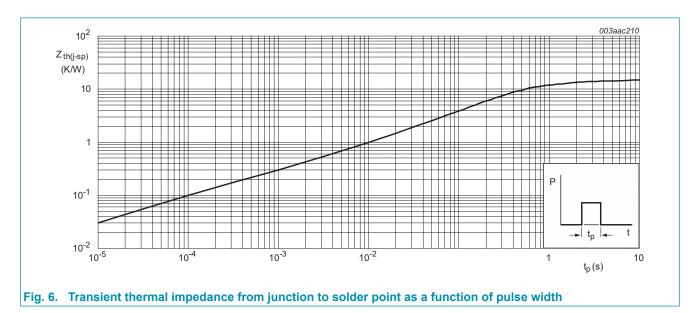


Z0109NN0 4Q Triac



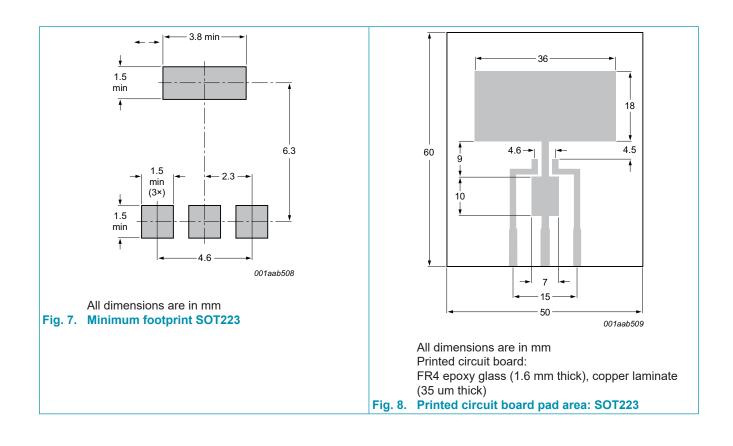
9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$R_{\text{th(j-sp)}}$	thermal resistance from junction to solder point	full cycle; <u>Fig 6</u>	-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to	in free air; printed circuit board mounted; minimum footprint; <u>Fig 7</u>	-	156	-	K/W
	ambient	in free air; printed circuit board mounted; pad area; Fig 8	-	70	-	K/W



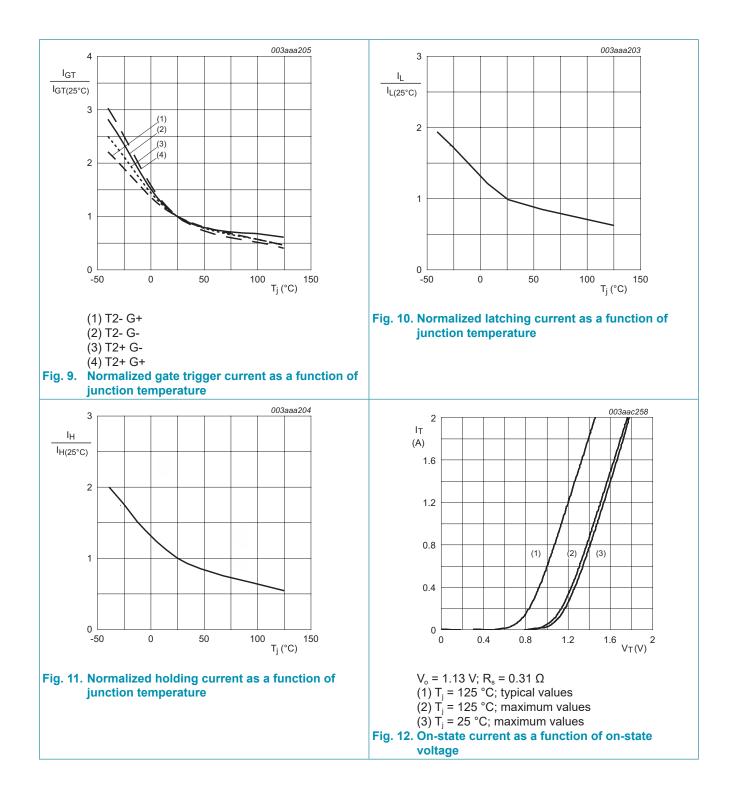
4Q Triac

Z0109NN0



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
Ι _{GT}	gate trigger current	$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; Fig. 9	0.4	-	10	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 9	0.4	-	10	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 9</u>	0.4	-	10	mA
		$V_{\rm D}$ = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; Fig. 9	0.4	-	10	mA
ΙL	latching current	V_{D} = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; Fig. 10	-	-	15	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; Fig. 10	-	-	30	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; Fig. 10	-	-	15	mA
		$V_{\rm D}$ = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; Fig. 10	-	-	15	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 11</u>	-	-	10	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 12</u>	-	1.3	1.6	V
V _{GT}	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 13	-	-	1	V
		V _D = 800 V; I _T = 0.1 A; T _j = 125 °C	0.2	-	-	V
I _D	off-state current	V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
Dynamic	characteristics		I			
dV _D /dt	rate of rise of off-state voltage $V_{DM} = 536 \text{ V}; \text{ T}_{j} = 110 \text{ °C}; (V_{DM} = 67\% \text{ of} \text{ V}_{DRM}); exponential waveform; gate open circuit; Fig. 14$		120	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{ T}_j = 110 \text{ °C};$ $dI_{com}/dt = 0.44 \text{ A/ms}; \text{ gate open circuit}$	2	-	-	V/µs



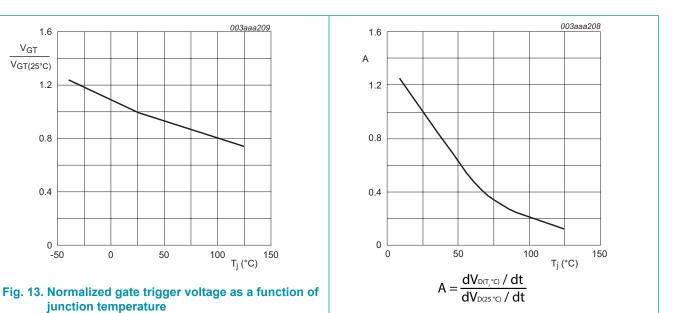


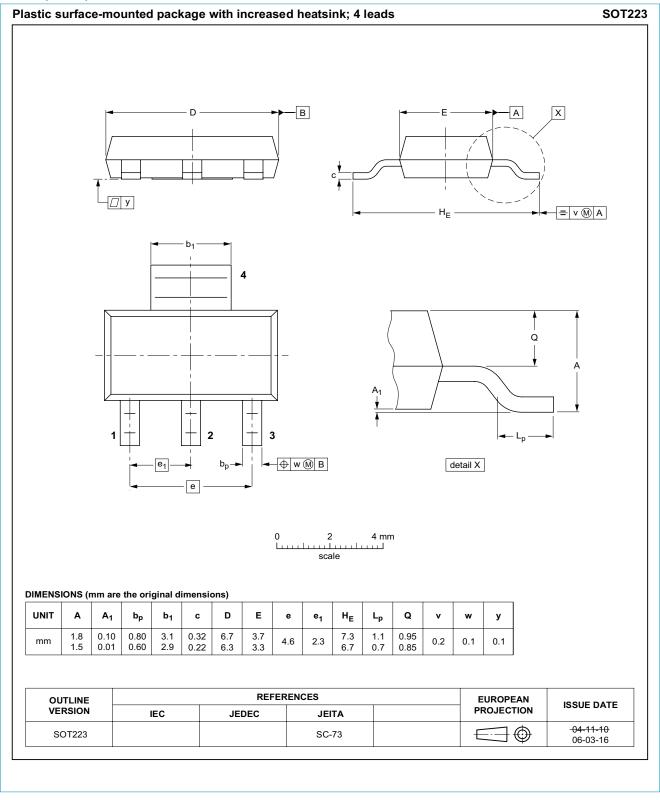
Fig. 14. Normalized critical rate of rise of off-state voltage as a function of junction temperature; typical values

Z0109NN0

4Q Triac

11. Package outline

Assembly factory: d & L



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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Z0109NN0 4Q Triac

13. Contents

1.	General description	1
2.	Features and benefits	1
3.	Applications	1
4.	Quick reference data	1
5.	Pinning information	2
6.	Ordering information	2
7.	Marking	2
8.	Limiting values	3
9.	Thermal characteristics	5
10	. Characteristics	7
11.	. Package outline	10
12	. Legal information	11
13	. Contents	13

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